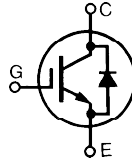


High Voltage, BiMOSFET™ Monolithic Bipolar MOS Transistor

IXBT42N300HV IXBH42N300HV

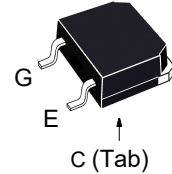


$$V_{CES} = 3000V$$

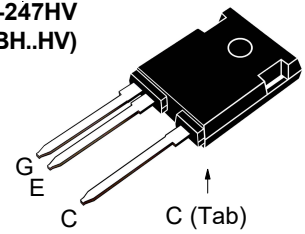
$$I_{C110} = 42A$$

$$V_{CE(sat)} \leq 3.0V$$

TO-268HV
(IXBT..HV)



TO-247HV
(IXBH..HV)



G = Gate C = Collector
E = Emitter Tab = Collector

| Symbol | Test Conditions | Maximum Ratings | |
|--|--|-----------------------|------------|
| V_{CES} | $T_C = 25^\circ C$ to $150^\circ C$ | 3000 | V |
| V_{CGR} | $T_J = 25^\circ C$ to $150^\circ C$, $R_{GE} = 1M\Omega$ | 3000 | V |
| V_{GES} | Continuous | ± 25 | V |
| V_{GEM} | Transient | ± 35 | V |
| I_{C25} | $T_C = 25^\circ C$ | 104 | A |
| I_{C110} | $T_C = 110^\circ C$ | 42 | A |
| I_{CM} | $T_C = 25^\circ C$, 1ms | 400 | A |
| SSOA (RBSOA) | $V_{GE} = 15V$, $T_{VJ} = 125^\circ C$, $R_G = 20\Omega$ Clamped Inductive Load | $I_{CM} = 84$ 1500 | A V |
| T_{SC} (SCSOA) | $V_{GE} = 15V$, $T_J = 125^\circ C$, $R_G = 82\Omega$, $V_{CE} = 1500V$, Non-Repetitive | 10 | μs |
| P_C | $T_C = 25^\circ C$ | 500 | W |
| T_J | | -55 ... +150 | $^\circ C$ |
| T_{JM} | | 150 | $^\circ C$ |
| T_{stg} | | -55 ... +150 | $^\circ C$ |
| T_L | Maximum Lead Temperature for Soldering | 300 | $^\circ C$ |
| T_{SOLD} | Plastic Body for 10s | 260 | $^\circ C$ |
| M_d | Mounting Torque (TO-247HV) | 1.13/10 | Nm/lb.in |
| Weight | TO-268HV | 4 | g |
| | TO-247HV | 6 | g |

Features

- High Voltage Package
- High Blocking Voltage
- High Peak Current Capability
- Low Saturation Voltage
- FBSOA
- SCSOA

Advantages

- Low Gate Drive Requirement
- High Power Density

Applications

- Laser Generators
- Capacitor Discharge Circuits
- AC Switches
- Protection Circuits

| Symbol | Test Conditions ($T_J = 25^\circ C$ Unless Otherwise Specified) | Characteristic Values | | |
|---------------|---|-----------------------|------------|-----------------------|
| | | Min. | Typ. | Max. |
| BV_{CES} | $I_C = 1mA$, $V_{GE} = 0V$ | 3000 | | V |
| $V_{GE(th)}$ | $I_C = 1mA$, $V_{CE} = V_{GE}$ | 3.0 | | 5.0 V |
| I_{CES} | $V_{CE} = 0.8 \cdot V_{CES}$, $V_{GE} = 0V$ $T_J = 125^\circ C$ | | 250 | 50 μA μA |
| I_{GES} | $V_{CE} = 0V$, $V_{GE} = \pm 25V$ | | | ± 200 nA |
| $V_{CE(sat)}$ | $I_C = 42A$, $V_{GE} = 15V$, Note 1 $T_J = 125^\circ C$ | | 2.5 3.1 | 3.0 V V |

| Symbol Test Conditions ($T_J = 25^\circ\text{C}$ Unless Otherwise Specified) | | Characteristic Values | | |
|--|--|-----------------------|------|-------------------------|
| | | Min. | Typ. | Max. |
| g_{fs} | $I_C = 42\text{A}, V_{CE} = 10\text{V}$, Note 1 | 28 | 45 | S |
| C_{ies} | $V_{CE} = 25\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$ | | 4780 | pF |
| C_{oes} | | | 170 | pF |
| C_{res} | | | 56 | pF |
| R_{Gi} | Gate Input Resistance | | 3.0 | Ω |
| Q_g | $I_C = 42\text{A}, V_{GE} = 15\text{V}, V_{CE} = 1000\text{V}$ | | 200 | nC |
| Q_{ge} | | | 28 | nC |
| Q_{gc} | | | 75 | nC |
| $t_{d(on)}$ | Resistive Switching Times, $T_J = 25^\circ\text{C}$ $I_C = 42\text{A}, V_{GE} = 15\text{V}$ $V_{CE} = 1500\text{V}, R_G = 20\Omega$ | | 72 | ns |
| t_r | | | 330 | ns |
| $t_{d(off)}$ | | | 445 | ns |
| t_f | | | 610 | ns |
| $t_{d(on)}$ | Resistive Switching Times, $T_J = 125^\circ\text{C}$ $I_C = 42\text{A}, V_{GE} = 15\text{V}$ $V_{CE} = 1500\text{V}, R_G = 20\Omega$ | | 72 | ns |
| t_r | | | 580 | ns |
| $t_{d(off)}$ | | | 460 | ns |
| t_f | | | 490 | ns |
| R_{thJC} | | | | 0.25 $^\circ\text{C/W}$ |
| R_{thCS} | TO-247HV | | 0.21 | $^\circ\text{C/W}$ |

Reverse Diode

| Symbol Test Conditions ($T_J = 25^\circ\text{C}$ Unless Otherwise Specified) | | Characteristic Values | | |
|--|---|-----------------------|------|---------------|
| | | Min. | Typ. | Max. |
| V_F | $I_F = 42\text{A}, V_{GE} = 0\text{V}$, Note 1 | | | 2.5 V |
| t_{rr} | $I_F = 21\text{A}, V_{GE} = 0\text{V}, -di_F/dt = 100\text{A}/\mu\text{s}$ $V_R = 100\text{V}, V_{GE} = 0\text{V}$ | | 1.7 | μs |
| I_{RM} | | | 43 | A |

Note 1. Pulse test, $t < 300\mu\text{s}$, duty cycle, $d < 2\%$.

Littelfuse reserves the right to change limits, test conditions and dimensions.

LF MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

| | | | | | | | | | |
|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|--------------|
| 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665 | 6,404,065 B1 | 6,683,344 | 6,727,585 | 7,005,734 B2 | 7,157,338 B2 |
| 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343 | 6,710,405 B2 | 6,759,692 | 7,063,975 B2 | |
| 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505 | 6,710,463 | 6,771,478 B2 | 7,071,537 | |

Fig. 1. Output Characteristics @ $T_J = 25^\circ\text{C}$

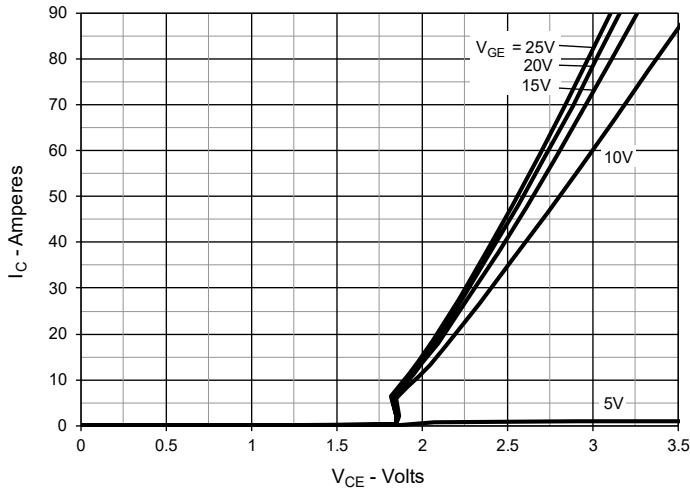


Fig. 2. Extended Output Characteristics @ $T_J = 25^\circ\text{C}$

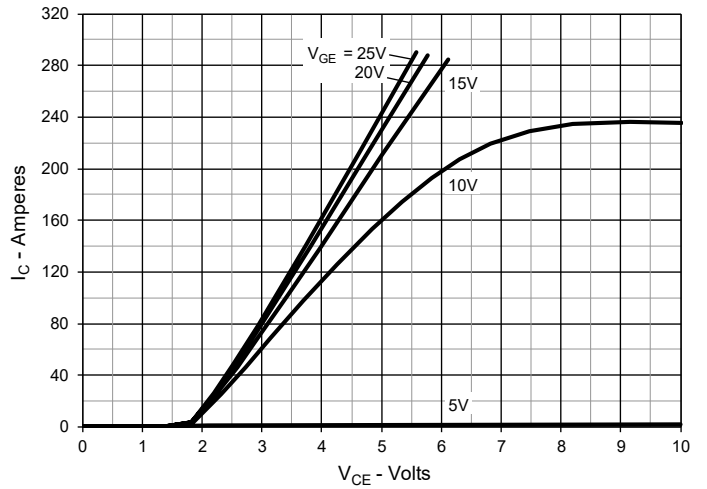


Fig. 3. Output Characteristics @ $T_J = 125^\circ\text{C}$

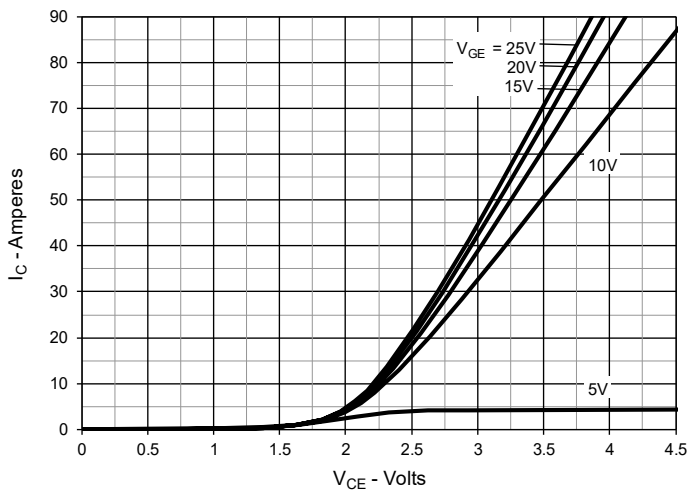


Fig. 4. Dependence of $V_{CE(sat)}$ on Junction Temperature

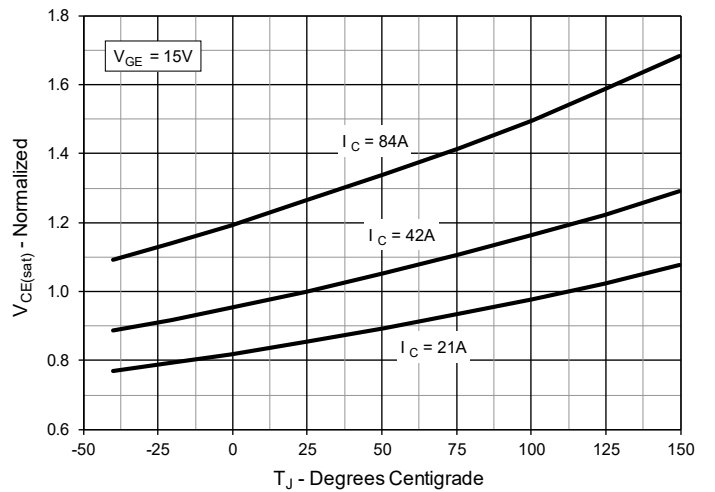


Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage

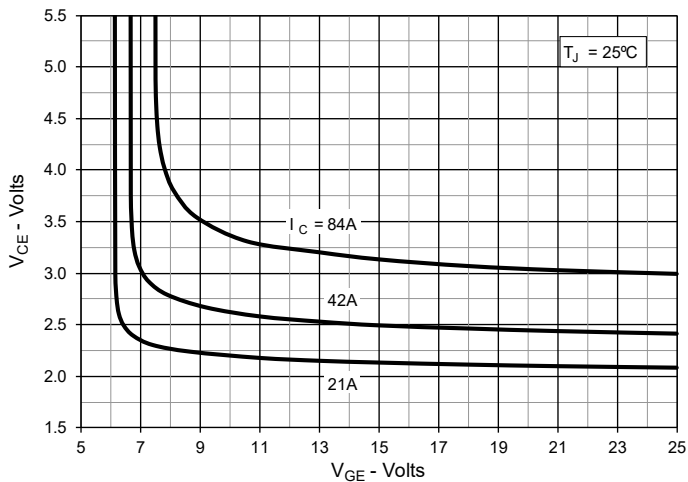


Fig. 6. Input Admittance

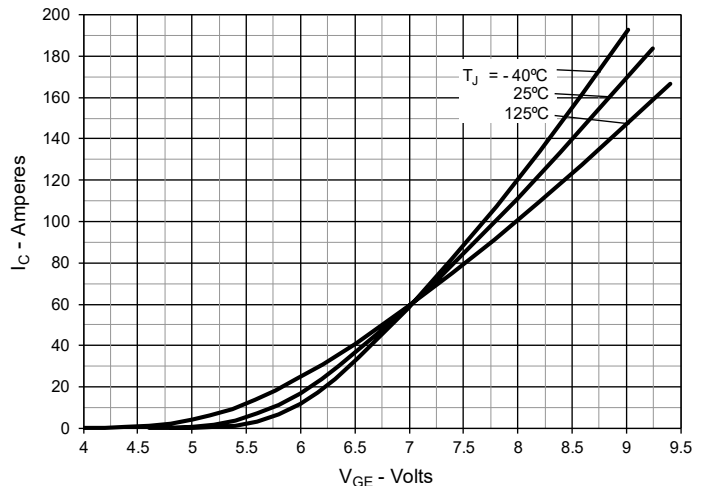


Fig. 7. Transconductance

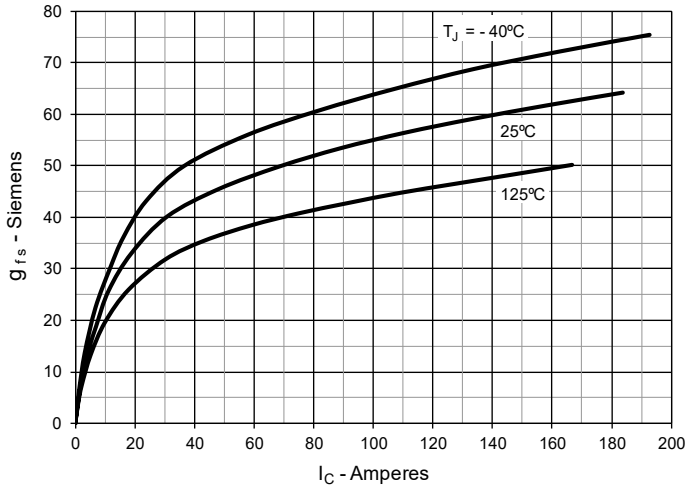


Fig. 8. Forward Voltage Drop of Intrinsic Diode

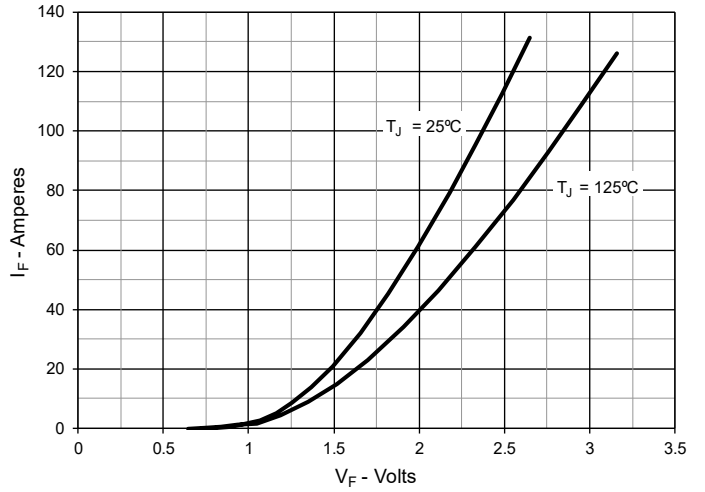


Fig. 9. Gate Charge

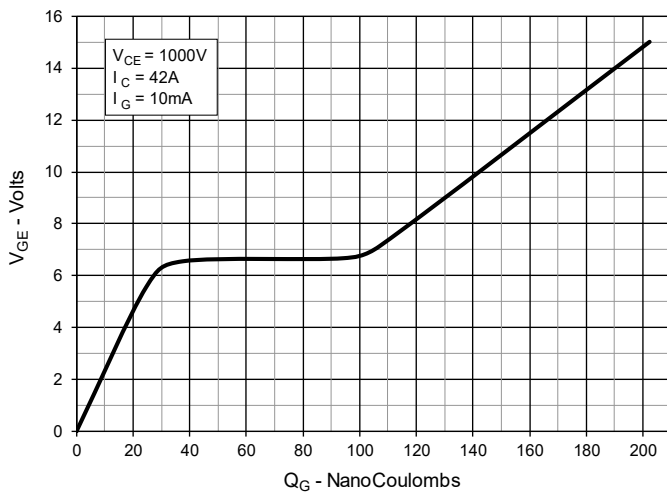


Fig. 10. Capacitance

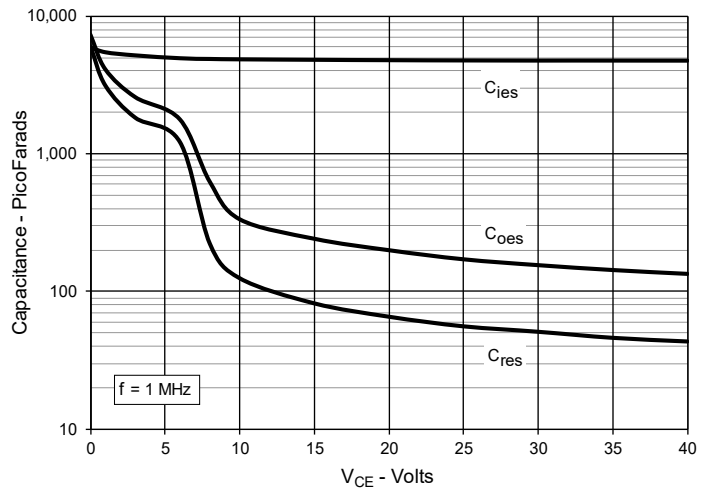


Fig. 11. Reverse-Bias Safe Operating Area

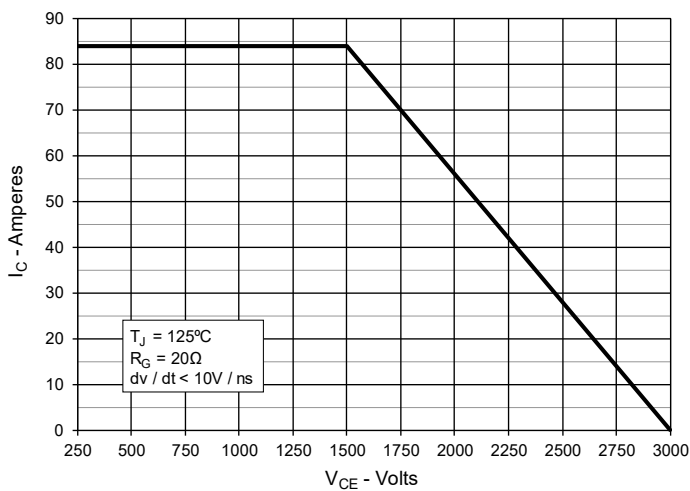


Fig. 12. Maximum Transient Thermal Impedance

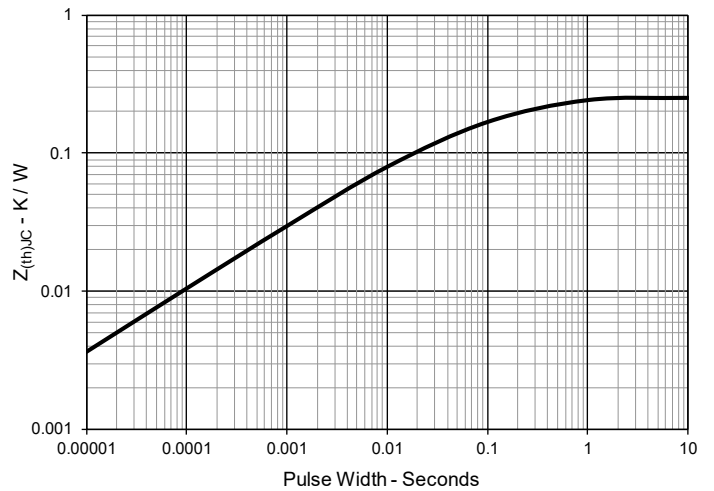


Fig. 13. Resistive Turn-on Rise Time vs. Junction Temperature

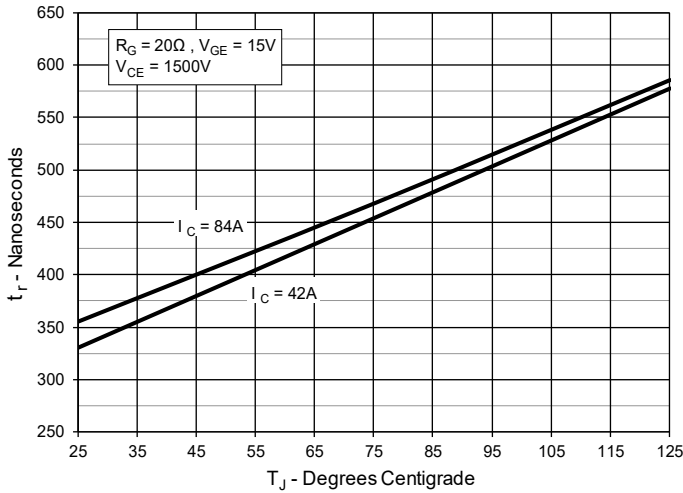


Fig. 14. Resistive Turn-on Rise Time vs. Collector Current

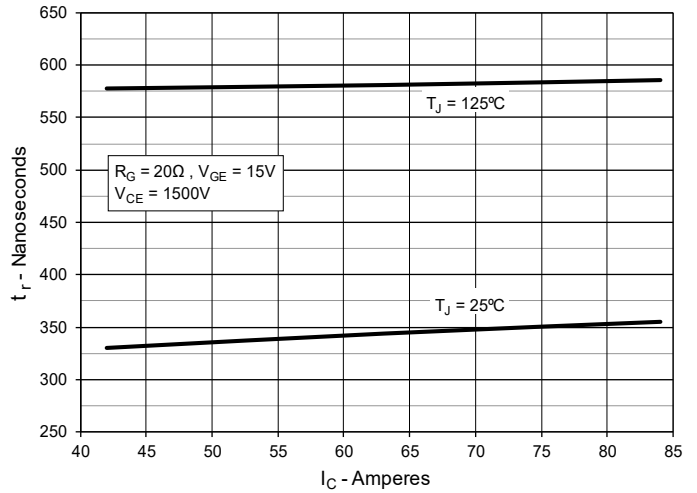


Fig. 15. Resistive Turn-on Switching Times vs. Gate Resistance

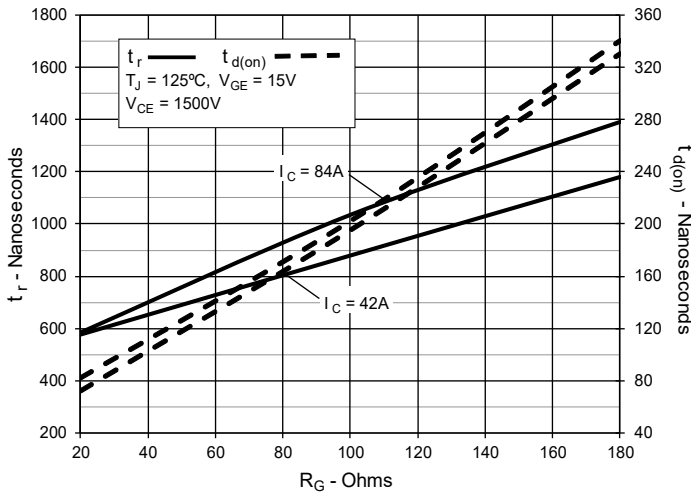


Fig. 16. Resistive Turn-off Switching Times vs. Junction Temperature

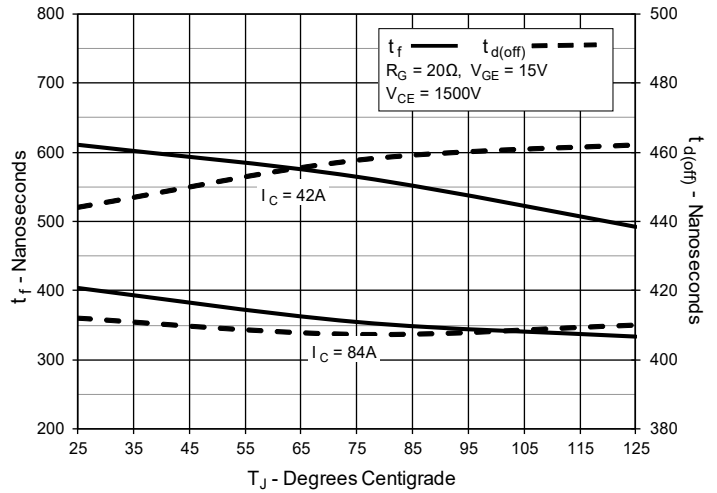


Fig. 17. Resistive Turn-off Switching Times vs. Collector Current

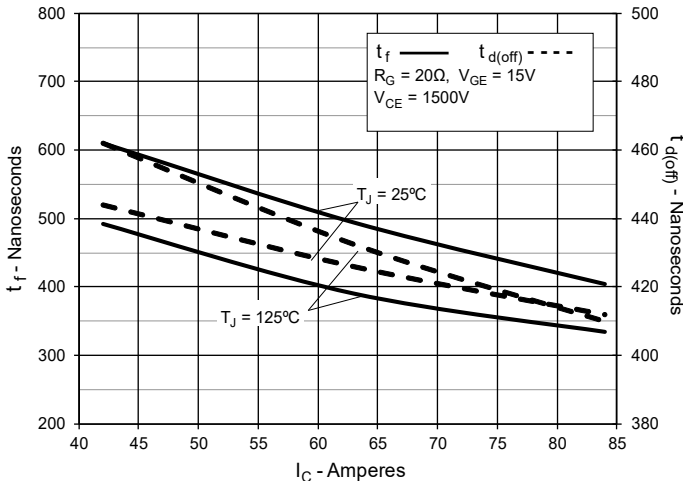


Fig. 18. Resistive Turn-off Switching Times vs. Gate Resistance

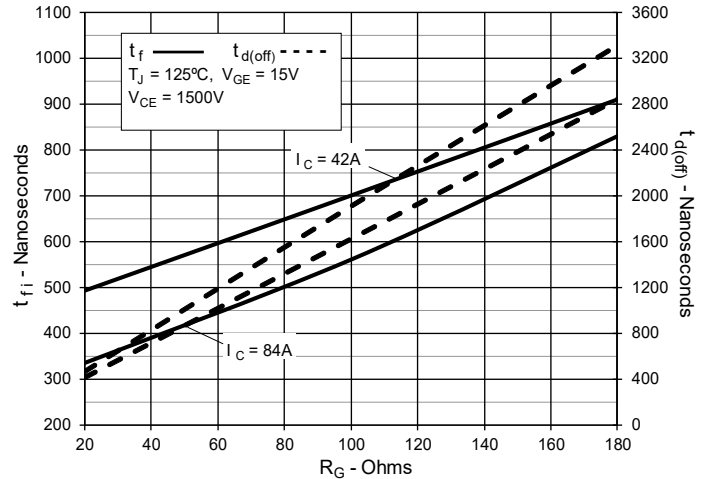


Fig. 19. Forward-Bias Safe Operating Area @ $T_C = 25^\circ\text{C}$

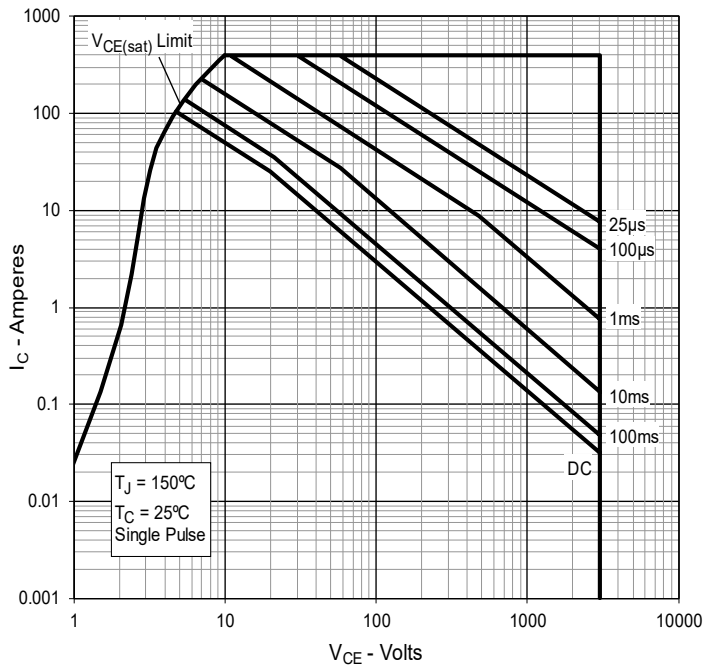
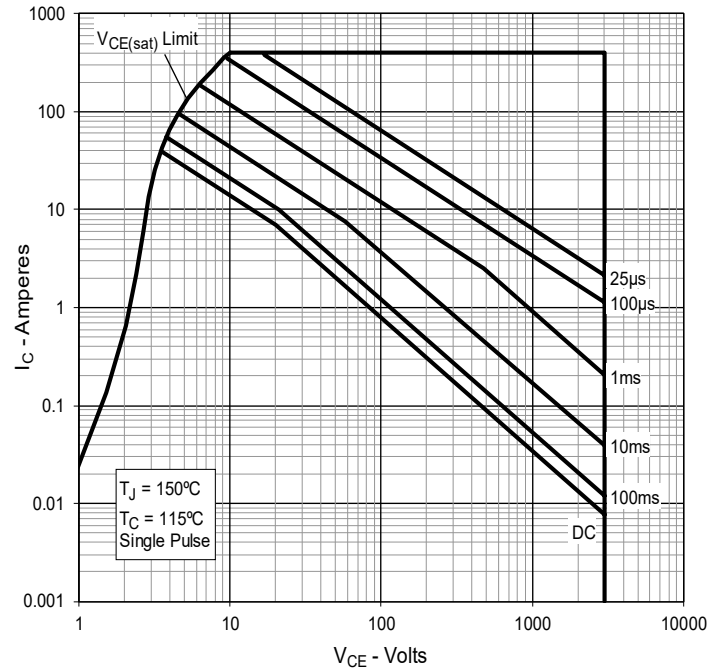
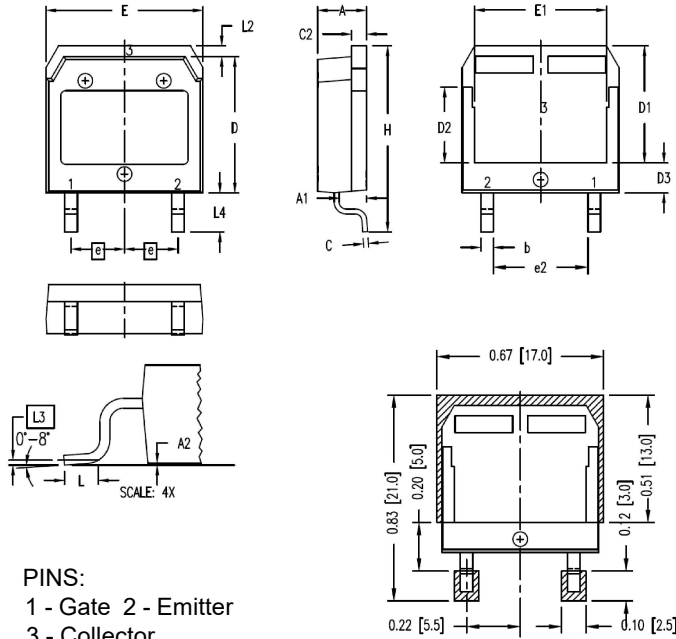


Fig. 20. Forward-Bias Safe Operating Area @ $T_C = 115^\circ\text{C}$

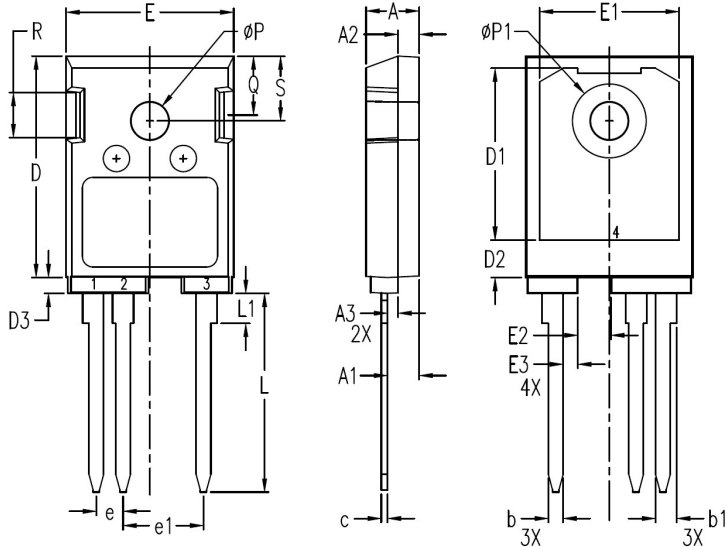


TO-268HV Outline



| SYM | INCHES | | MILLIMETER | |
|------|----------|------|------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .193 | .201 | 4.90 | 5.10 |
| A1 | .106 | .114 | 2.70 | 2.90 |
| A2 | .001 | .010 | 0.02 | 0.25 |
| b | .045 | .057 | 1.15 | 1.45 |
| C | .016 | .026 | 0.40 | 0.65 |
| C2 | .057 | .063 | 1.45 | 1.60 |
| D | .543 | .551 | 13.80 | 14.00 |
| D1 | .465 | .476 | 11.80 | 12.10 |
| D2 | .295 | .307 | 7.50 | 7.80 |
| D3 | .114 | .126 | 2.90 | 3.20 |
| E | .624 | .632 | 15.85 | 16.05 |
| E1 | .524 | .535 | 13.30 | 13.60 |
| e | .215 BSC | | 5.45 BSC | |
| (e2) | .374 | .386 | 9.50 | 9.80 |
| H | .736 | .752 | 18.70 | 19.10 |
| L | .067 | .079 | 1.70 | 2.00 |
| L2 | .039 | .045 | 1.00 | 1.15 |
| L3 | .010 BSC | | 0.25 BSC | |
| L4 | .150 | .161 | 3.80 | 4.10 |

TO-247HV Outline



| SYM | INCHES | | MILLIMETERS | |
|-----|----------|------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .193 | .201 | 4.90 | 5.10 |
| A1 | .114 | .122 | 2.90 | 3.10 |
| A2 | .075 | .083 | 1.90 | 2.10 |
| A3 | .035 | .043 | 0.90 | 1.10 |
| b | .053 | .059 | 1.35 | 1.50 |
| b1 | .075 | .083 | 1.90 | 2.10 |
| c | .022 | .030 | 0.55 | 0.75 |
| D | .819 | .843 | 20.80 | 21.40 |
| D1 | .638 | .646 | 16.20 | 16.40 |
| D2 | .134 | .146 | 3.40 | 3.70 |
| D3 | .055 | .063 | 1.40 | 1.60 |
| E | .622 | .638 | 15.80 | 16.20 |
| E1 | .520 | .528 | 13.20 | 13.40 |
| E2 | .118 | .126 | 3.00 | 3.20 |
| E3 | .051 | .059 | 1.30 | 1.50 |
| e | .100 BSC | | 2.54 BSC | |
| e1 | .300 BSC | | 7.62 BSC | |
| L | .724 | .748 | 18.40 | 19.00 |
| L1 | .106 | .118 | 2.70 | 3.00 |
| øP | .138 | .142 | 3.50 | 3.60 |
| øP1 | .272 | .280 | 6.90 | 7.10 |
| Q | .216 | .224 | 5.50 | 5.70 |
| R | .165 | .169 | 4.20 | 4.30 |
| S | .240 | .248 | 6.10 | 6.30 |



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